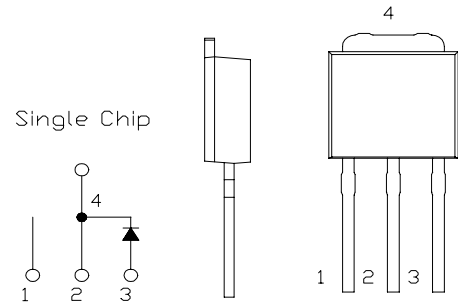


SBD Type : EA20QS10

OUTLINE DRAWING

FEATURES

- * TO-251AA Case
- * Low Forward Voltage drop
- * Low Power Loss
- * High Surge Capability
- * 40 Volts thru 100 Volts Types Available



Maximum Ratings

Approx Net Weight:0.35g

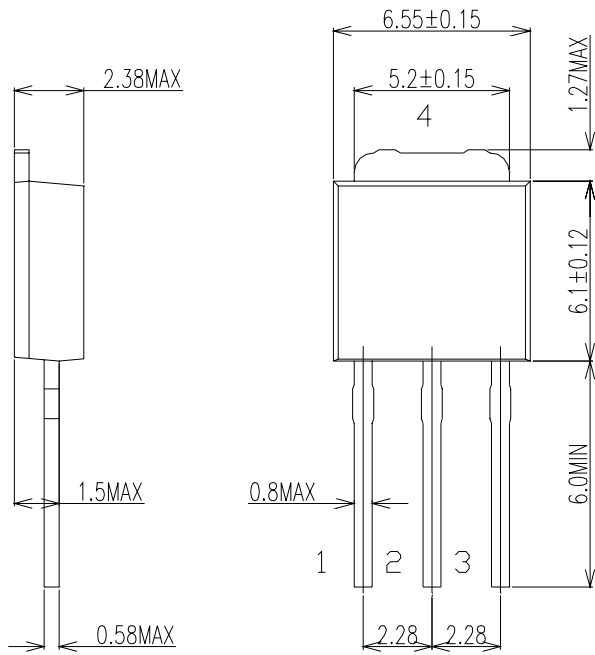
Rating		Symbol	EA20QS10			Unit
Repetitive Peak Reverse Voltage		V_{RRM}	100			V
Average Rectified Output Current	P.C.Board mounted *	I_O	1.7	$T_a=28^{\circ}C$	50Hz Half Sine Wave Resistive Load	A
	-		1.7	$T_c=138^{\circ}C$		
RMS Forward Current		$I_{F(RMS)}$	2.67			A
Surge Forward Current		I_{FSM}	40	50Hz Half Sine Wave, 1cycle, Non-repetitive		A
Operating Junction Temperature Range		T_{jw}	- 40 to + 150			$^{\circ}C$
Storage Temperature Range		T_{stg}	- 40 to + 150			$^{\circ}C$

Electrical • Thermal Characteristics

Characteristics		Symbol	Conditions	Min	Typ	Max	Unit
Peak Reverse Current		I_{RM}	$T_j=25^{\circ}C, V_{RM}=V_{RRM}$	-	-	1.0	mA
Peak Forward Voltage		V_{FM}	$T_j=25^{\circ}C, I_{FM}= 2 A$	-	-	0.85	V
Thermal Resistance	Junction to Ambient	$R_{th(j-a)}$	P.C.Board mounted *	-	-	80	$^{\circ}C/W$
	Junction to Case	$R_{th(j-c)}$	-	-	-	7	$^{\circ}C/W$

* Print Land = 20x20 mm

EA20QS10 OUTLINE DRAWING (Dimensions in mm)



Single Chip

